



Product Summary

BV _{DSS}	RDS(ON) Max	I _D Max T _A = +25°C		
40)/	11mΩ @ V _{GS} = -10V	-10.1A		
-40V	15mΩ @ V _{GS} = -4.5V	-8.8A		

Description & Applications

This MOSFET is designed to meet the stringent requirements of automotive applications. It is qualified to AEC-Q101, supported by a PPAP and is ideal for use in:

- DC-DC converters
- Power-management functions
- Analog switches

40V P-CHANNEL ENHANCEMENT MODE MOSFET

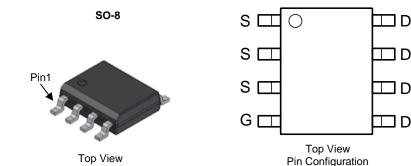
Features and Benefits

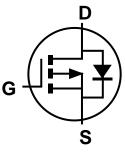
- 100% Unclamped Inductive Switch (UIS) Test in Production
- Low Input Capacitance
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- The DMP4015SSSQ is suitable for automotive applications requiring specific change control; this part is AEC-Q101 qualified, PPAP capable, and manufactured in IATF 16949 certified facilities.

https://www.diodes.com/guality/product-definitions/

Mechanical Data

- Package: SO-8
- Package Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections: See Diagram
- Terminals: Finish Matte Tin Annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208 (3)
- Weight: 0.074 grams (Approximate)





Equivalent Circuit

Ordering Information (Note 4)

Part Number	Package	Packing		
Fait Nulliber	Fackage	Qty.	Carrier	
DMP4015SSSQ-13	SO-8	2,500	Tape & Reel	

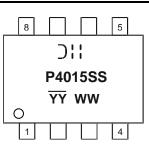
Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.

2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information



)|| = Manufacturer's Marking P4015SS = Product Type Marking Code \overline{YYWW} = Date Code Marking $YY \text{ or } \overline{YY}$ = Year (ex: 23 = 2023) WW = Week (01 to 53)



Maximum Ratings (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit			
Drain-Source Voltage		V _{DSS}	-40	V		
Gate-Source Voltage			Vgss	±25	V	
Continuous Drain Current (Nata 5) \/ 40\/	Steady	T _A = +25°C	1-	-9.1	٨	
Continuous Drain Current (Note 5) V _{GS} = -10V	State	T _A = +70°C	ID	-7.2	A	
Continuous Drain Current (Note 5) V_{GS} = -4.5V	Steady	T _A = +25°C		-7.8	•	
	State	T _A = +70°C	ID	-6.2	A	
Continuous Drain Current (Note 6) V_{GS} = -10V	Steady State	T _A = +25°C		-10.1	•	
		T _A = +70°C	ID	-8	A	
Continuous Drain Current (Note 6) V_{GS} = -4.5V	Steady	T _A = +25°C		-8.8		
	State	T _A = +70°C	ID	-7	A	
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%)			I _{DM}	-100	А	
Avalanche Current (Note 7)			las	-22	А	
Avalanche Energy (Note 7)			Eas	242	mJ	

Thermal Characteristics

Characteristic	Symbol	Value	Unit
Total Power Dissipation (Note 5)	PD	1.45	W
Thermal Resistance, Junction to Ambient (Note 5)	Reja	88	°C/W
Total Power Dissipation (Note 6)	PD	1.82	W
Thermal Resistance, Junction to Ambient (Note 6)	Reja	70	°C/W
Thermal Resistance, Junction to Case (Note 6)	R _{0JC}	7.6	°C/W
Operating and Storage Temperature Range	TJ, TSTG	-55 to +150	°C

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 8)		l					
Drain-Source Breakdown Voltage	BVDSS	-40	_	_	V	V _{GS} = 0V, I _D = -250µA	
Zero Gate Voltage Drain Current	IDSS	_	_	-1	μA	$V_{DS} = -40V, V_{GS} = 0V$	
Gate-Source Leakage	lgss			±100	nA	$V_{GS} = \pm 25V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 8)							
Gate Threshold Voltage	VGS(TH)	-1.5	-2	-2.5	V	$V_{DS} = V_{GS}$, $I_D = -250 \mu A$	
Static Drain-Source On-Resistance	Deserve	—	7	11	mΩ	V _{GS} = -10V, I _D = -9.8A	
Static Drain-Source On-Resistance	R _{DS(ON)}		9	15	11152	$V_{GS} = -4.5V, I_{D} = -9.8A$	
Forward Transfer Admittance	Y _{fs}	_	26	_	s	V _{DS} = -20V, I _D = -9.8A	
Diode Forward Voltage (Note 5)	V _{SD}	_	-0.7	-1	V	$V_{GS} = 0V, I_{S} = -1A$	
DYNAMIC CHARACTERISTICS (Note 9)							
Input Capacitance	Ciss	—	4,234	_		$V_{DS} = -20V, V_{GS} = 0V$ f = 1MHz	
Output Capacitance	Coss		1,036	_	pF		
Reverse Transfer Capacitance	Crss	—	526	_			
Gate Resistance	Rg		7.77	_	Ω	$V_{DS} = 0V, V_{GS} = 0V, f = 1MHz$	
Total Gate Charge	Qg	_	47.5	_		V _{DS} = -20V, V _{GS} = -5V I _D = -9.8A	
Gate-Source Charge	Qgs	_	14.2	_	nC		
Gate-Drain Charge	Q _{gd}	_	13.5	_			
Turn-On Delay Time	td(on)	_	13.2	_		$V_{GS} = -10V, V_{DD} = -20V, R_{g} = 6\Omega,$	
Turn-On Rise Time	t _R	_	10	_	ns		
Turn-Off Delay Time	tD(OFF)		302.7	_	115	$I_D = -1A, R_L = 20\Omega$	
Turn-Off Fall Time	t⊨		137.9	_			

5. Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout. Notes:

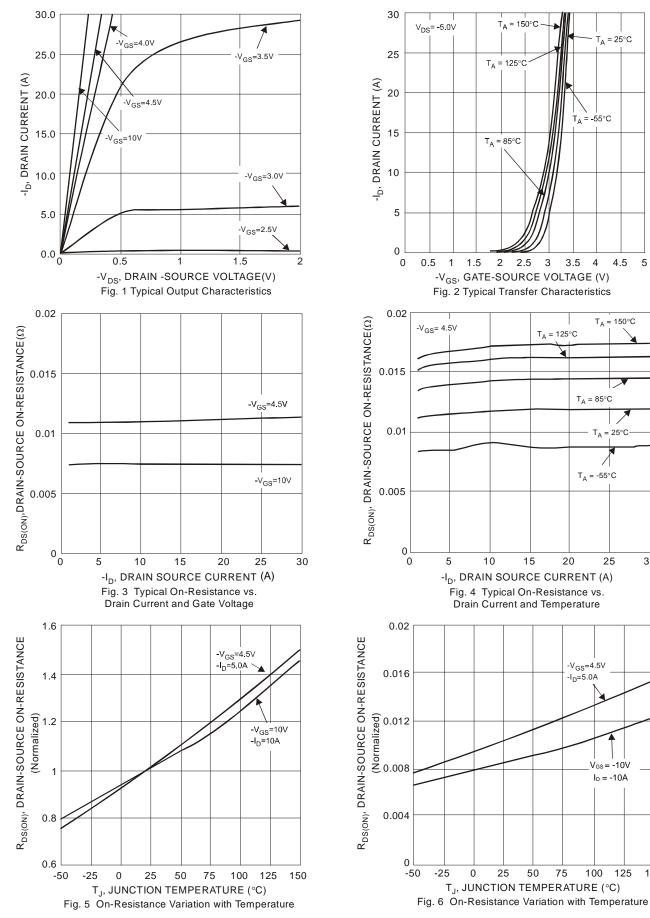
6. Device mounted on FR-4 substrate PC board, 2oz copper, with 1-inch square copper plate.

7. UIS in production with L = 1mH, $T_J = +25^{\circ}$ C. 8. Short duration pulse test used to minimize self-heating effect. 9. Guaranteed by design. Not subject to production testing.



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DMP4015SSSQ Document number: DS36682 Rev. 6 - 2

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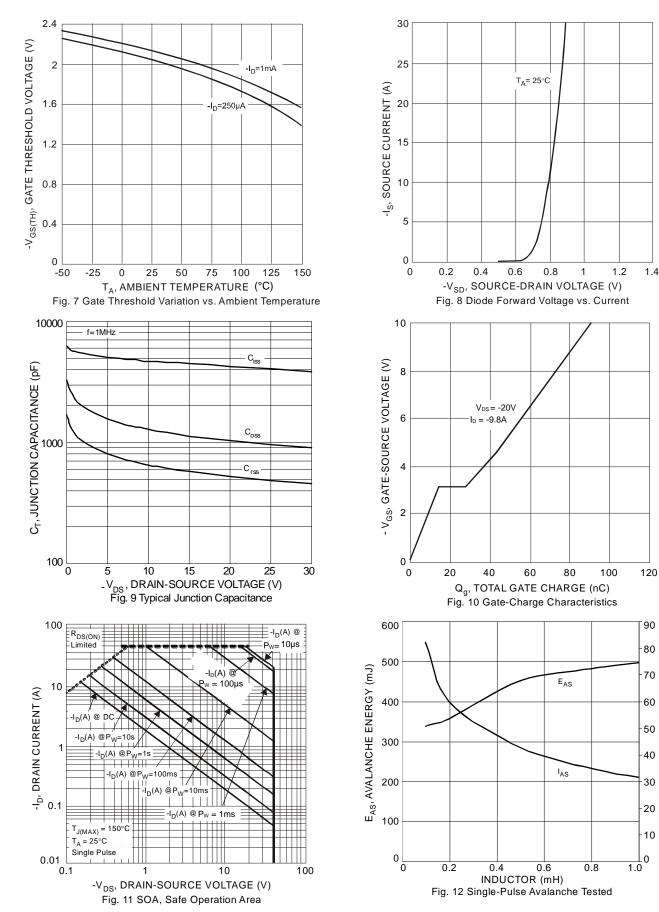
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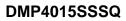


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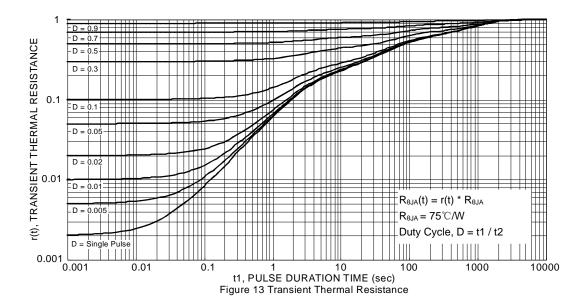
AS, AVALANCHE CURRENT (A)

70





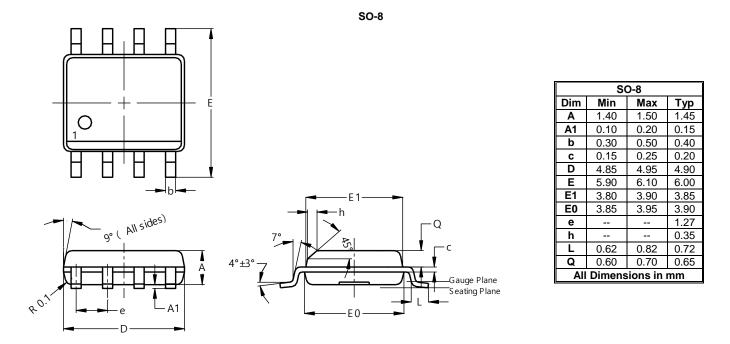






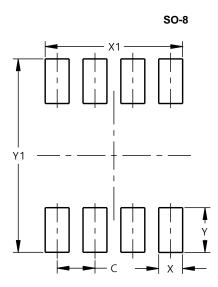
Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.



Suggested Pad Layout

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Dimensions	Value (in mm)
С	1.27
Х	0.802
X1	4.612
Y	1.505
Y1	6.50



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